

Full - Bridge MOSFET Power Module

> OUT1 OUT2

VBUS

Q3

Q4

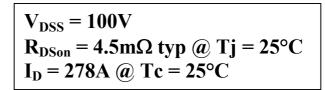
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OUT

OUT2

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C





- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

#### Features

**G3** 

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S3

**G4** 

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<u>s</u>2

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G4

- Power MOS V<sup>®</sup> FREDFETs
  - Low R<sub>DSon</sub>
  - Low input and Miller capacitance
  - Low gate charge
  - Fast intrinsic reverse diode
  - Avalanche energy rated
  - Very rugged
- Kelvin source for easy drive
  - Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration

#### Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

#### Absolute maximum ratings

G1

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**S**1

G2

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S2

Q2

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VBUS

Symbol	Parameter		Max ratings	Unit
V <sub>DSS</sub>	Drain - Source Breakdown Voltage		100	V
I <sub>D</sub>	Continuous Drain Current	$T_c = 25^{\circ}C$	278	
ID	Continuous Drain Current	$T_c = 80^{\circ}C$	207	А
I <sub>DM</sub>	Pulsed Drain current		1100	
V <sub>GS</sub>	Gate - Source Voltage		±30	V
R <sub>DSon</sub>	Drain - Source ON Resistance		5	mΩ
PD	Maximum Power Dissipation $T_c = 25^{\circ}C$		780	W
I <sub>AR</sub>	Avalanche current (repetitive and non repetitive)		100	А
E <sub>AR</sub>	Repetitive Avalanche Energy		50	mJ
E <sub>AS</sub>	Single Pulse Avalanche Energy		3000	111J

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



### All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit	
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 100V$ $T_j = 25^{\circ}C$			200		
		$V_{GS} = 0V, V_{DS} = 80V$ $T_j = 125^{\circ}C$			1000	μA	
R <sub>DS(on)</sub>	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 125A$		4.5	5	mΩ	
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 5mA$	2		4	V	
I <sub>GSS</sub>	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$			±200	nA	

#### **Dynamic Characteristics**

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C <sub>iss</sub>	Input Capacitance	$V_{GS} = 0V$		20		
C <sub>oss</sub>	Output Capacitance	$V_{\rm DS} = 25 V$		8		nF
C <sub>rss</sub>	Reverse Transfer Capacitance	f=1MHz		2.9		
Qg	Total gate Charge	$V_{GS} = 10V$		700		
Q <sub>gs</sub>	Gate – Source Charge	$V_{Bus} = 50V$		120		nC
$Q_{gd}$	Gate – Drain Charge	$I_{\rm D} = 250 {\rm A}$		360		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive switching @ 125°C		80		
Tr	Rise Time	$V_{GS} = 15V$ $V_{Bus} = 66V$		165		na
T <sub>d(off)</sub>	Turn-off Delay Time	$I_{\rm D} = 250 \text{ A}$		280		ns
$T_{f}$	Fall Time	$R_G = 2.5 \Omega$		135		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		1.1		
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 250A, R_G = 2.5\Omega$		1.2		mJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		1.22		
E <sub>off</sub>	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 250A, R_G = 2.5\Omega$		1.28		mJ

#### Source - Drain diode ratings and characteristics

Symbol	Characteristic	<b>Test Conditions</b>		Min	Тур	Max	Unit
Is	Continuous Source current		$Tc = 25^{\circ}C$			278	А
	(Body diode)		$Tc = 80^{\circ}C$			207	A
$V_{SD}$	Diode Forward Voltage	$V_{GS} = 0V, I_S = -250A$				1.3	V
dv/dt	Peak Diode Recovery <b>1</b>					5	V/ns
t <sub>rr</sub>	Reverse Recovery Time		$T_j = 25^{\circ}C$			190	ns
		$I_{\rm S} = -250 A$ $V_{\rm R} = 50 V$	$T_j = 125^{\circ}C$			370	115
Q <sub>rr</sub>	Reverse Recovery Charge	$di_{\rm S}/dt = 200 {\rm A}/{\rm \mu s}$	$T_j = 25^{\circ}C$		0.8		μC
	Reverse Receivery Charge		$T_j = 125^{\circ}C$		3.4		μυ

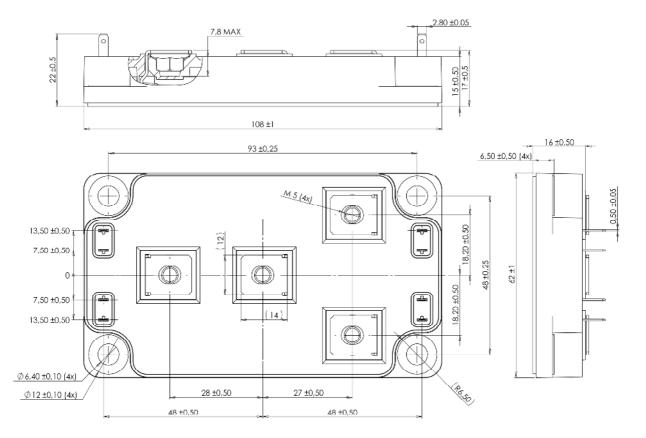
• dv/dt numbers reflect the limitations of the circuit rather than the device itself.  $I_S \le -278A$  di/dt  $\le 200A/\mu s$   $V_R \le V_{DSS}$   $T_j \le 150^{\circ}C$ 



### Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R <sub>thJC</sub>	Junction to Case Thermal Resistance					0.16	°C/W
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T <sub>J</sub>	Operating junction temperature range		-40		150	°C	
T <sub>STG</sub>	Storage Temperature Range			-40			125
T <sub>C</sub>	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	19.111
Wt	Package Weight					300	g

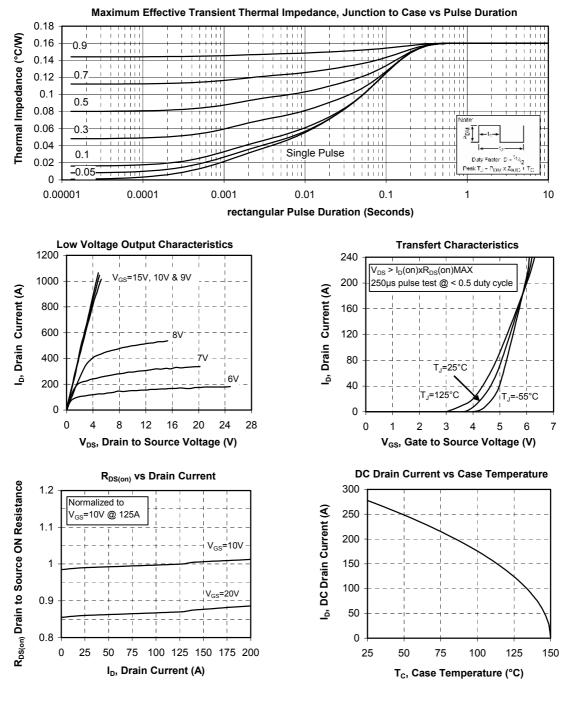
### SP6 Package outline (dimensions in mm)



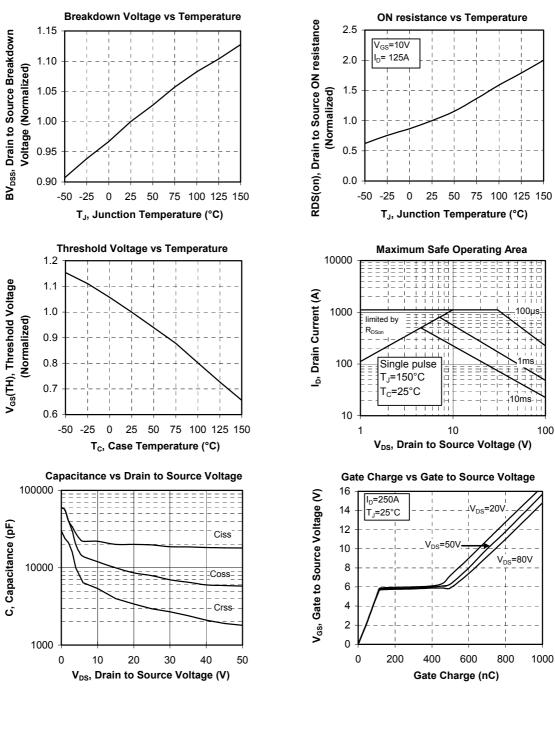
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com



#### **Typical Performance Curve**





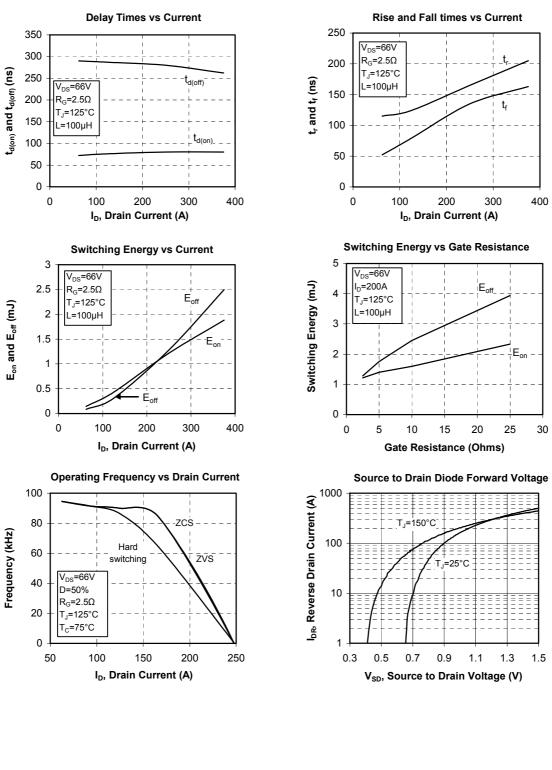


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